

## T510X476K035ATA055

**General Information** 

Series

Dielectric

T510 Auto, Tantalum, MnO2 Tantalum, Multi-Anode, 47 uF, 10%, 35 VDC, SMD, MnO2, Multi-Anode, LowESR, Auto, AEC-Q200, 55 mOhms, 7343, Height Max = 4.3mm

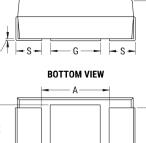
**CATHODE (-) END VIEW** 



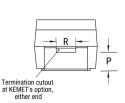
B

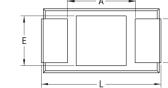
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ANODE	(+)	END	VIEW





Click here for the 3D model.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	4mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
А	3.8mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	1.7mm REF
R	1mm REF
Х	0.1mm +/-0.1mm

т

2.4mm +/-0.1mm		Failure Rate
3.8mm MIN		Resistance
0.5mm +/-0.15mm		Ripple Current
3.5mm REF	Rippie Current	
3.5mm REF		Leakage Current
1.7mm REF		
1mm REF		

Style	SMD Chip
Description	SMD, MnO2, Multi-Anode, LowESR, Auto, AEC-Q200
Features	Automotive, Low ESR
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Component Weight	430.15 mg
MSL	1

T510 Auto

MnO2 Tantalum

Specifications	/
Capacitance	47 uF
Capacitance Tolerance	10%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
<b>Dissipation Factor</b>	8% 120Hz 25C
Failure Rate	N/A
Resistance	55 mOhms (100kHz 25C)
Ripple Current	2216 mA (rms, 100kHz 25C), 1994.4 mA (rms, 85C), 886.4 mA (rms, 125C)
Leakage Current	16.5 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.